## NSN 5961-01-219-7784

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View Online at https://aerobasegroup.com/nsn/5961-01-219-7784 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 repetitive peak reverse voltage and 600.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 12.50 amperes forward current, total rms horsepower metric and 200.00 amperes peak forward surge current absolute **Power Rating Per Characteristic:** 40.0 watts small-signal input power, common-collector blank **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0